# NSN 5961-01-229-7012

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# Inclosure Material:

Metal

**Overall Length:** 

1.252 inches

# **Overall Height:**

0.270 inches

# **Overall Width:**

0.700 inches

# **Mounting Facility Quantity:**

2

#### Internal Configuration:

Junction contact-darlington connected

#### Joint Electronic Device Engineering Council/jedec/case Outline Designation:

#### To-66

#### Electrode Internally-electrically Connected To Case:

Collector

#### Mounting Method:

Unthreaded hole

#### Features Provided:

Hermetically sealed case

#### Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

60.0 collector to base voltage/static/emitter open and 60.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage,

static, collector open

#### **Current Rating Per Characteristic:**

4.00 amperes source cutoff current and 80.00 milliamperes source cutoff current

#### **Power Rating Per Characteristic:**

50.0 watts small-signal input power, common-collector absolute

#### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius ambient air

#### **Special Features:**

Junction pattern arrangement: pnp

#### **Test Data Document:**

78711-t235a398 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;

excludes any specification, standard or other document that may be referenced in a basic governing drawing)

#### Terminal Type And Quantity:

2 pin and 1 case

Shelf Life:

N/a

#### Unit Of Measure:

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Demilitarization:

No

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